Doc No. TT4-EA-14623

Revision. 1

**Product Standards** 

Zener Diode

Unit: mm

#### DZ2622000L

## **Panasonic**

### DZ2622000L

### Silicon epitaxial planar type

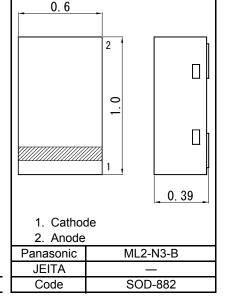
For constant voltage / For surge absorption circuit DZ27220 in ML2 type package

#### ■ Features

- Excellent rising characteristics of zener current IZ
- · Low zener operating resistance RZ
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol : CG

#### ■ Packaging

Embossed type (Thermo-compression sealing): 10 000 pcs / reel (standard)



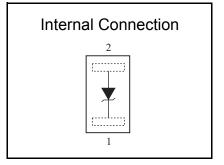
#### ■ Absolute Maximum Ratings Ta = 25 °C

Symbol	Rating	Unit
IFRM	200	mA
PT	100	mW
ESD	±8	kV
Tj	150	°C
Tstg	-55 to +150	°C
	PT ESD Tj	IFRM         200           PT         100           ESD         ±8           Tj         150

Note) \*1 PT = 100 mW achieved with a printed circuit board.

\*2 Test method:IEC61000\_4\_2

( C = 150 pF , R = 330  $\Omega$  , Contact discharge : 10 times )



#### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 10 mA			1.0	V
Zener voltage *1, *2	VZ	IZ = 5 mA	20.90		23.10	V
Zener operating resistance	RZ	IZ = 5 mA			80	Ω
Zener rise operating resistance	RZK	IZ = 0.5 mA			100	Ω
Reverse current	IR	VR = 17 V			0.05	μΑ
Temperature coefficient of zener voltage *3	SZ	IZ = 5 mA		22.2		mV/°C

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.
  - 2. Absolute frequency of input and output is 5 MHz.
  - 3. \*1 The temperature must be controlled 25 °C for VZ mesurement. VZ value measured at other temperature must be adjusted to VZ ( 25 °C )
    - \*2 VZ guaranteed 20 ms after current flow.
    - \*3 Tj = 25 °C to 150 °C

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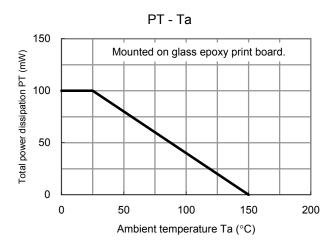
**Product Standards** 

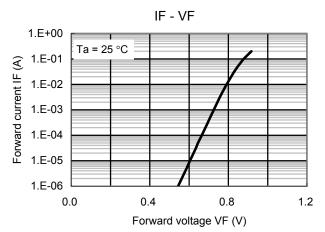
Zener Diode

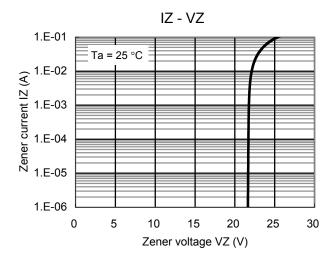
#### DZ2622000L

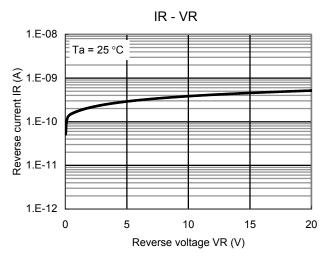
# **Panasonic**

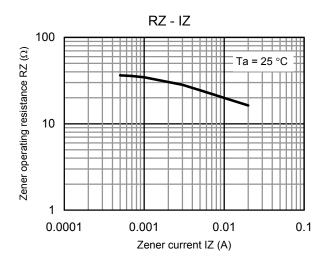
## Technical Data (reference)

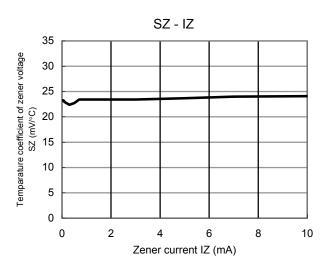












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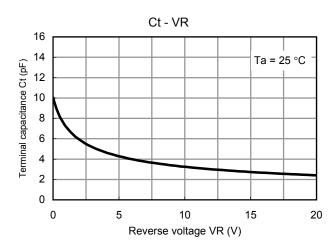
**Product Standards** 

Zener Diode

DZ2622000L

# **Panasonic**

## Technical Data (reference)



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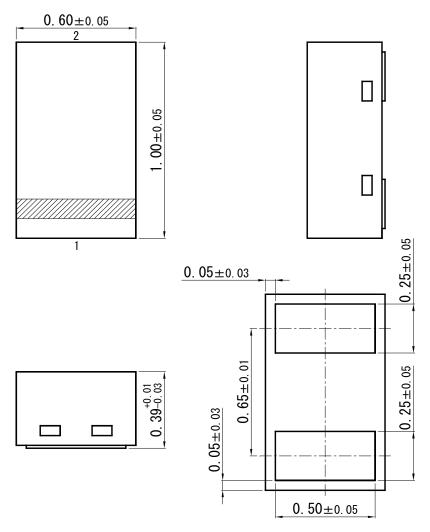
**Product Standards** 

Zener Diode

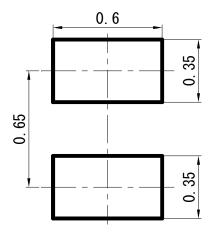
### DZ2622000L

# **Panasonic**

ML2-N3-B Unit: mm



■ Land Pattern (Reference) (Unit: mm)



Established : 2013-04-11 Revised : ###-##-##

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